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- Support Mixed-Mode Signal Operation (5-V Input and Output Voltages With 3.3-V V_{CC})
- Support Unregulated Battery Operation Down to 2.7 V
- Typical V_{OLP} (Output Ground Bounce) <0.8 V at V_{CC} = 3.3 V, $T_A = 25^{\circ}C$
- B-Port Outputs Have Equivalent 22-Ω Series Resistors, So No External Resistors Are Required
- I_{off} and Power-Up 3-State Support Hot Insertion
- Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors
- Latch-Up Performance Exceeds 500 mA Per JESD 17
- ESD Protection Exceeds JESD 22
 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)

description/ordering information

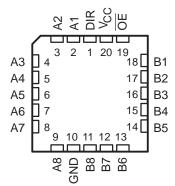
These octal bus transceivers are designed specifically for low-voltage (3.3-V) V_{CC} operation, but with the capability to provide a TTL interface to a 5-V system environment.

These devices are designed for asynchronous communication between data buses. They transmit data from the A bus to the B bus or from

SN54LVTH2245 J OR W PACKAGE								
SN74LVTH2245 DB, DGV, DW, NS, OR PW PACKAGE								
(TOP VIEW)								

DIR [1	U	20	Vcc
A1 [2		19] OE
A2 [3		18] B1
A3 [4		17] B2
A4 [5		16] B3
A5 [6		15	B4
A6 [7		14] B5
A7 [8		13] B6
A8 [9		12] B7
GND [10		11] B8

SN54LVTH2245 . . . FK PACKAGE (TOP VIEW)



the B bus to the A bus, depending on the logic level at the direction-control (DIR) input. The output-enable (\overline{OE}) input can be used to disable the devices so the buses are effectively isolated.

TA	PACKA	GEŤ	ORDERABLE PART NUMBER	TOP-SIDE MARKING		
		Tube	SN74LVTH2245DW	1) (7) 100 (5)		
	SOIC – DW	Tape and reel	SN74LVTH2245DWR	LVTH2245		
–40°C to 85°C	SOP – NS	Tape and reel	SN74LVTH2245NSR	LVTH2245		
	SSOP – DB	SOP – DB Tape and reel SN74LVTH2245DBR		LK245		
	70000 DW/	Tube	SN74LVTH2245PW	11/045		
	TSSOP – PW	Tape and reel	SN74LVTH2245PWR	LK245		
	TVSOP – DGV	Tape and reel	SN74LVTH2245DGVR	LK245		
	CDIP – J	Tube	SNJ54LVTH2245J	SNJ54LVTH2245J		
–55°C to 125°C	CFP – W	Tube	SNJ54LVTH2245W	SNJ54LVTH2245W		
	LCCC – FK	Tube	SNJ54LVTH2245FK	SNJ54LVTH2245FK		

ORDERING INFORMATION

[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



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description/ordering information (continued)

Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level. Use of pullup or pulldown resistors with the bus-hold circuitry is not recommended.

The B-port outputs, which are designed to source or sink up to 12 mA, include equivalent $22-\Omega$ series resistors to reduce overshoot and undershoot.

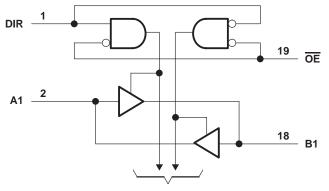
When V_{CC} is between 0 and 1.5 V, the devices are in the high-impedance state during power up or power down. However, to ensure the high-impedance state above 1.5 V, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

These devices are fully specified for hot-insertion applications using I_{off} and power-up 3-state. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the devices when they are powered down. The power-up 3-state circuitry places the outputs in the high-impedance state during power up and power down, which prevents driver conflict.

FUNCTI	ON	TABLE	

INP	UTS							
OE	DIR	OPERATION						
L	L	B data to A bus						
L	н	A data to B bus						
н	Х	Isolation						

logic diagram (positive logic)



To Seven Other Channels



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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage range, V _{CC} 0.5 V to 4.6 V Input voltage range, V _I (see Note 1)0.5 V to 7 V
Voltage range applied to any output in the high-impedance or power-off state, V _O (see Note 1)
Voltage range applied to any output in the high state, V_O (see Note 1)0.5 V to V_{CC} + 0.5 V
Current into any output in the low state, IO: SN54LVTH2245 (A port)
SN74LVTH2245 (A port)
B port
Current into any output in the high state, I _O (see Note 2): SN54LVTH2245 (A port)
SN74LVTH2245 (A port) 64 mA
B port
Input clamp current, I _{IK} (V _I < 0)
Output clamp current, I_{OK} (V _O < 0)
Package thermal impedance, θ _{JA} (see Note 3): DB package
DGV package
DW package
NS package
PW package
Storage temperature range, T _{stg} –65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

2. This current flows only when the output is in the high state and $V_O > V_{CC}$.

3. The package thermal impedance is calculated in accordance with JESD 51-7.

recommended operating conditions (see Note 4)

			SN54LVT	H2245	SN74LVT		
			MIN	MAX	MIN	MAX	UNIT
VCC	Supply voltage		2.7	3.6	2.7	3.6	V
VIH	High-level input voltage		2		2		V
VIL	Low-level input voltage			0.8		0.8	V
VI	Input voltage			5.5		5.5	V
	Plack land and an and an	A port		-24		-32	
ЮН	High-level output current	h-level output current B port		-12		-12	mA
	Level and and an entered	A port	20	48		64	
IOL	Low-level output current	B port	20	12		12	mA
$\Delta t/\Delta v$	Input transition rise or fall rate	Outputs enabled	Q	10		10	ns/V
$\Delta t / \Delta V_{CC}$	Power-up ramp rate		200		200		μs/V
Т _А	Operating free-air temperature	-55	125	-40	85	°C	

NOTE 4: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

			SN5	4LVTH2	2245	SN7	4LVTH2	245			
PAI	RAMETER	TEST C	ONDITIONS	MIN	TYP†	MAX	MIN	TYP†	MAX	UNIT	
VIK		V _{CC} = 2.7 V,	lj = -18 mA			-1.2			-1.2	V	
		V _{CC} = 2.7 V to 3.6 V,	I _{OH} = -100 μA	V _{CC} -0	.2		V _{CC} -0				
		V _{CC} = 2.7 V,	IOH = -8 mA	2.4			2.4				
.,	A port		I _{OH} = -24 mA	2						.,	
VOH		$V_{CC} = 3 V$	I _{OH} = -32 mA				2			V	
	Dimont	V_{CC} = 2.7 V to 3.6 V,	I _{OH} = -100 μA	V _{CC} -0	.2		V _{CC} -0	.2			
	B port	V _{CC} = 3 V,	I _{OH} = -12 mA	2			2				
			I _{OL} = 100 μA			0.2			0.2		
		$V_{CC} = 2.7 V$	I _{OL} = 24 mA			0.5			0.5		
	A port /OL		I _{OL} = 16 mA			0.4			0.4		
Max		N== 0.1	I _{OL} = 32 mA			0.5			0.5	V	
VOL		$V_{CC} = 3 V$	I _{OL} = 48 mA			0.55				V	
			I _{OL} = 64 mA						0.55		
	Dimont	V_{CC} = 2.7 V to 3.6 V,	l _{OL} = 100 μA			0.2			0.2		
	B port	V _{CC} = 3 V,	I _{OL} = 12 mA		E	0.8			0.8		
	Control in guite	V _{CC} = 3.6 V,	$V_I = V_{CC} \text{ or } GND$		24	±1			±1		
		V _{CC} = 0 or 3.6 V,	V, V _I = 5.5 V		S.	10			10		
lj.			V _I = 5.5 V	4	20.	20			20	μA	
	A or B ports‡	V _{CC} = 3.6 V	VI = VCC	P.)	1			1	1	
			$V_{I} = 0$			-5			-5		
loff		$V_{CC} = 0,$	V_{I} or V_{O} = 0 to 4.5 V						±100	μA	
		$\lambda = 2 \lambda$	V _I = 0.8 V	75			75				
l(hold)	A or B ports	V _{CC} = 3 V	V _I = 2 V	-75	-75		-75			μA	
•1(11010)		V _{CC} = 3.6 V§,	$V_{I} = 0$ to 3.6 V						500 -750	μ	
IOZPU		$\frac{V_{CC}}{OE} = 0$ to 1.5 V, $V_{O} = 0$	0.5 V to 3 V,			±100*			±100	μA	
IOZPD		$\frac{V_{CC}}{OE}$ = 1.5 V to 0, V _O = OE = don't care	0.5 V to 3 V,			±100*			±100	μA	
		V _{CC} = 3.6 V,	Outputs high			0.19		0.1	0.19		
ICC		$I_{O} = 0,$	Outputs low			5		3	5	mA	
		$V_I = V_{CC}$ or GND	Outputs disabled			0.19		0.1	0.19		
ΔI_{CC} ¶		V_{CC} = 3 V to 3.6 V, On Other inputs at V _{CC} or				0.2			0.2	mA	
Ci		V _I = 3 V or 0			4			4		pF	
Cio		V _O = 3 V or 0			9			9		pF	

* On products compliant to MIL-PRF-38535, this parameter is not production tested.

[†] All typical values are at V_{CC} = 3.3 V, T_A = 25° C.

[‡] Unused terminals are at V_{CC} or GND.

§ This is the bus-hold maximum dynamic current. It is the minimum overdrive current required to switch the input from one state to another.

This is the increase in supply current for each input that is at the specified TTL voltage level, rather than V_{CC} or GND.



SN54LVTH2245, SN74LVTH2245 **3.3-V ABT OCTAL BUS TRANSCEIVERS** WITH 3-STATE OUTPUTS SCBS707E – SEPTEMBER 1997 – REVISED OCTOBER 2003

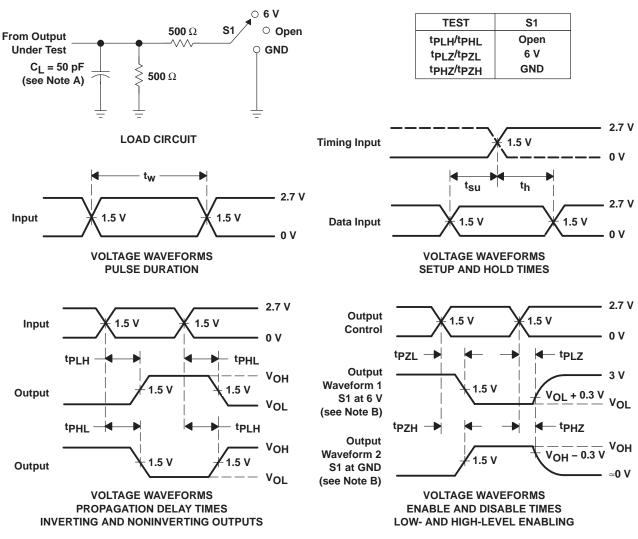
switching characteristics over recommended operating free-air temperature range, C_L = 50 pF (unless otherwise noted) (see Figure 1)

				SN54LV	TH2245			SN7	4LVTH2	245		
PARAMETER	FROM (INPUT)	TO (OUTPUT)		V _{CC} = 3.3 V ± 0.3 V		V _{CC} = 2.7 V		V _{CC} = 3.3 V ± 0.3 V			V _{CC} = 2.7 V	
			MIN	MAX	MIN	MAX	MIN	TYP†	MAX	MIN	MAX	
^t PLH	А	В	1	4.6		5.3	1.1	2.9	4.4		5.1	
^t PHL	A	D	1	4.6		5.3	1.1	2.6	4.4		5.1	ns
^t PLH	В	^	1	3.7	1	4.2	1.1	2.2	3.5		4	
^t PHL	D	A	1	3.7	ر آل	4.2	1.1	2	3.5		4	ns
^t PZH	OE	•	1.2	5.7	JE1	7.4	1.3	3.1	5.5		7.1	
^t PZL	OE	A	1.6	5.7	2	6.8	1.7	3.2	5.5		6.5	ns
^t PHZ	OE	А	2	6.2		6.8	2.2	3.6	5.9		6.5	ns
^t PLZ	UE	A	2	5.3		5.5	2.2	3.4	5		5.1	115
^t PZH		2	1.2	6 .4		7.6	1.3	3.5	6.2		7.3	
^t PZL	ŌĒ	В	1.6	6.4		7.5	1.7	3.7	6.2		7.3	ns
^t PHZ	OE		2	6.1		6.8	2.2	3.9	5.9		6.5	
^t PLZ	UE	В	2	5.7		5.9	2.2	3.7	5.4		5.7	ns

 $\overline{\dagger}$ All typical values are at V_{CC} = 3.3 V, T_A = 25°C.



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PARAMETER MEASUREMENT INFORMATION

NOTES: A. C₁ includes probe and jig capacitance.

B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.

- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_Q = 50 Ω , t_f \leq 2.5 ns, t_f \leq 2.5 ns.
- D. The outputs are measured one at a time with one transition per measurement.

E. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms





6-Feb-2020

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
SN74LVTH2245DBR	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LK245	Samples
SN74LVTH2245DGVR	ACTIVE	TVSOP	DGV	20	2000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LK245	Samples
SN74LVTH2245DW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVTH2245	Samples
SN74LVTH2245DWR	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVTH2245	Samples
SN74LVTH2245PW	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LK245	Samples
SN74LVTH2245PWR	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LK245	Samples
SN74LVTH2245PWRG4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LK245	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <= 1000ppm threshold. Antimony trioxide based flame retardants must also meet the <= 1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.



PACKAGE OPTION ADDENDUM

6-Feb-2020

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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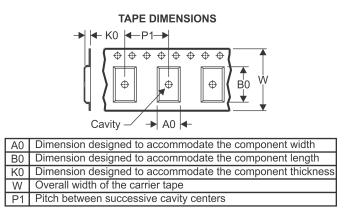
PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal	1				1	1						1
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVTH2245DBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
SN74LVTH2245DGVR	TVSOP	DGV	20	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LVTH2245DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
SN74LVTH2245PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1

TEXAS INSTRUMENTS

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PACKAGE MATERIALS INFORMATION

2-Oct-2019



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVTH2245DBR	SSOP	DB	20	2000	367.0	367.0	38.0
SN74LVTH2245DGVR	TVSOP	DGV	20	2000	367.0	367.0	35.0
SN74LVTH2245DWR	SOIC	DW	20	2000	367.0	367.0	45.0
SN74LVTH2245PWR	TSSOP	PW	20	2000	367.0	367.0	38.0

MECHANICAL DATA

PLASTIC SMALL-OUTLINE

MPDS006C - FEBRUARY 1996 - REVISED AUGUST 2000

DGV (R-PDSO-G**)

24 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.
- D. Falls within JEDEC: 24/48 Pins MO-153

14/16/20/56 Pins – MO-194



PW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



NOTES:

A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994. β . This drawing is subject to change without notice.

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.

Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.

E. Falls within JEDEC MO-153



LAND PATTERN DATA



NOTES: Α. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
 C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



DW0020A



PACKAGE OUTLINE

SOIC - 2.65 mm max height

SOIC



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



DW0020A

EXAMPLE BOARD LAYOUT

SOIC - 2.65 mm max height

SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



DW0020A

EXAMPLE STENCIL DESIGN

SOIC - 2.65 mm max height

SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



DB0020A



PACKAGE OUTLINE

SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-150.



DB0020A

EXAMPLE BOARD LAYOUT

SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



DB0020A

EXAMPLE STENCIL DESIGN

SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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